Unitized Semiconductor Devices - Page 1 of 1



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Inclosure	Material:
meiosure	material.

Ceramic

Overall Length:

0.770 inches

Terminal Length:

0.230 inches

Overall Height:

0.120 inches

Overall Width:

0.310 inches

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

Mo-036ab

Component Name And Quantity:

4 transistor

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

-200.0 drain to gate voltage all transistor and -200.0 drain to source voltage all transistor and -20.0 gate to source voltage all transistor

Current Rating Per Characteristic:

-1.60 amperes off-state current, peak all transistor

Power Rating Per Characteristic:

1.4 watts total power dissipation all transistor

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Terminal Type And Quantity:

14 pin

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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